DIFFERENTIAL COMPARATORS

MCC1711 MCC1711C

Advance Information

MONOLITHIC DUAL DIFFERENTIAL VOLTAGE COMPARATOR CHIP

 \ldots designed for use in level detection, low-level sensing, and memory applications.

The MCC1711 and MCC1711C employ phosphorsilicate passivation that protects the entire die surface area, including metalization interconnects. All dice have a minimum gold-backed thickness of 4000 Angstroms. The interconnecting metalization and bonding pads are of evaporated aluminum.

- Differential Input —
 Input Offset Voltage = 1.0 mV
 Offset Voltage Drift = 5.0 μV/°C
- Fast Response Time 40 ns
- Output Compatible with All Saturating Logic Forms Vout = +4.5 V to -0.5 V Typical
- Low Output Impedance 200 Ohms

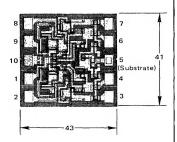
MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit Vdc	
Power Supply Voltage	V ⁺	+14		
	V-	-7.0	Vdc	
Differential Input Signal	V _{in}	±5.0	Volts	
Common Mode Input Swing	CMVin	±7.0	Volts	
Peak Load Current	ال	50	mA	
Operating Temperature Range	TA	-55 to +125	°C	
Junction Temperature Range	TJ	-65 to +150	°C	

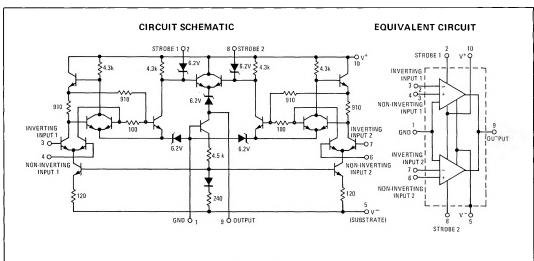
DUAL DIFFERENTIAL COMPARATOR CHIP INTEGRATED CIRCUIT

MONOLITHIC SILICON EPITAXIAL PASSIVATED

OUTLINE DIMENSIONS and BONDING DIAGRAM



All dimensions are nominal and in mils (10⁻³ inches). Die Dimensions
Thickness = 8.0
Bonding Pads = 4.0 x 4.0



This is advance information on a new introduction and specifications are subject to change without notice

ELECTRICAL CHARACTERISTICS (each comparator) (V+ = +12 Vdc, V- = -6.0 Vdc, TA = 25°C unless otherwise noted)

Characteristic		MCC1711			MCC1711C			
	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage (V _o = 1.4 Vdc)	Vio	-	1.0	3.5	-	1.0	5.0	mVdc
Input Bias Current (V _O = 1.4 Vdc)	lр	-	25	75	-	25	100	μAdc
Output Resistance	Rout	_	200	-	-	200	-	Ohms
Positive Output Voltage $(V_{in} \ge 10 \text{ mVdc}, 0 \le I_0 \le 5.0 \text{ mA})$	VOH	2.5	3.2	5.0	2.5	3.2	5.0	Vdc
Negative Output Voltage (V _{in} ≥ -10 mVdc)	VOL	-1.0	-0.5	0	-1.0	-0.5	0	Vdc
Strobed Output Level (V _{strobe} ≤ 0.3 Vdc)	VOL(st)	~1.0	-	0	-1.0	- 3	0	Vdc
Output Sink Current $(V_{in} \ge -10 \text{ mV}, V_0 \ge 0)$	¹s	0.5	8.0	-	0.5	0.8		mAdc
Strobe Current (V _{strobe} = 100 mVdc)	ı _{st}	_	1.2	2.5		1.2	2.5	mAdc
Response Time $(V_b = 5.0 \text{ mV} + V_{io})$	tR		40	-	Ť	40	-	ns
Strobe Release Time	tsR	-	12	-	-	12	-	ns
Power Supply Current	1 _D +	_	8.6		-	8.6	_	mAdc
(V _o ≤ 0 Vdc)	'D"	-	3.9		-	3.9	-	
Power Consumption		-	130	200	-	130	200	mW

See current MC1711/1711C data sheet for additional information.

PACKAGING AND HANDLING

The MCC1711/MCC1711C dual differential comparator is now available as a single monolithic die or encapsulated in the TO-91, TO-100, and TO-116 hermetic packages. The phosphorsilicate passivation protects the metalization and active area of the die but care must be exercised when removing the dice from the shipping carrier to avoid scratching the bonding pads. A vacuum pickup is useful for handling of dice. Tweezers are not recommended for this purpose.

The non-spill type shipping carrier consists of a compartmentalized tray and fitted cover. Die are placed in the carrier with geometry side up.